

1-Line Bi-directional TVS Diode

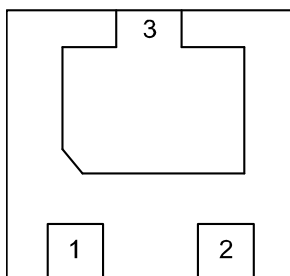
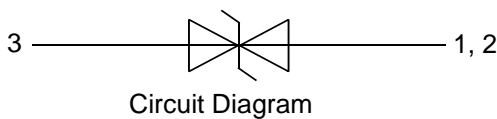
Description

The PESDU1211P4-3 is a high power TVS, utilizing to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive lines. The PESDU1211P4-3 complies with the IEC 61000-4-2 (ESD) with $\pm 30\text{kV}$ air and $\pm 30\text{kV}$ contact discharge. It is assembled into a 3-pin DFN2020-3 lead-free package. Each device will protect one line. The combination of small size, and high surge capability makes them ideal for use in applications such as cellular phones, LCD displays, USB, and multi media card interfaces.

Features

- 4700W peak pulse power (8/20 μs)
- Operating voltage: 12V
- Ultra low clamping voltage
- One power line protects
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
Air discharge: $\pm 30\text{kV}$
Contact discharge: $\pm 30\text{kV}$
 - IEC61000-4-5 (Lightning) 200A (8/20 μs)
- RoHS Compliant

Dimensions and Pin Configuration



Transparent top view

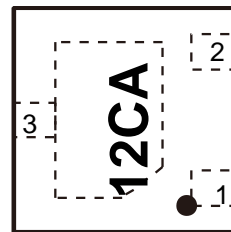
Mechanical Characteristics

- Package: DFN2020-3
- Case Material: “Green” Molding Compound
- Moisture Sensitivity: Level 1 per J-STD-020
- Marking Information: See Below

Applications

- Power Management
- Industrial Application
- Power Supply Protection

Marking Information



.12CA = Device Making Code

Ordering Information

Part Number	Shipping	Reel Size
PESDU1211P4-3	3000/Tape & Reel	7 inch

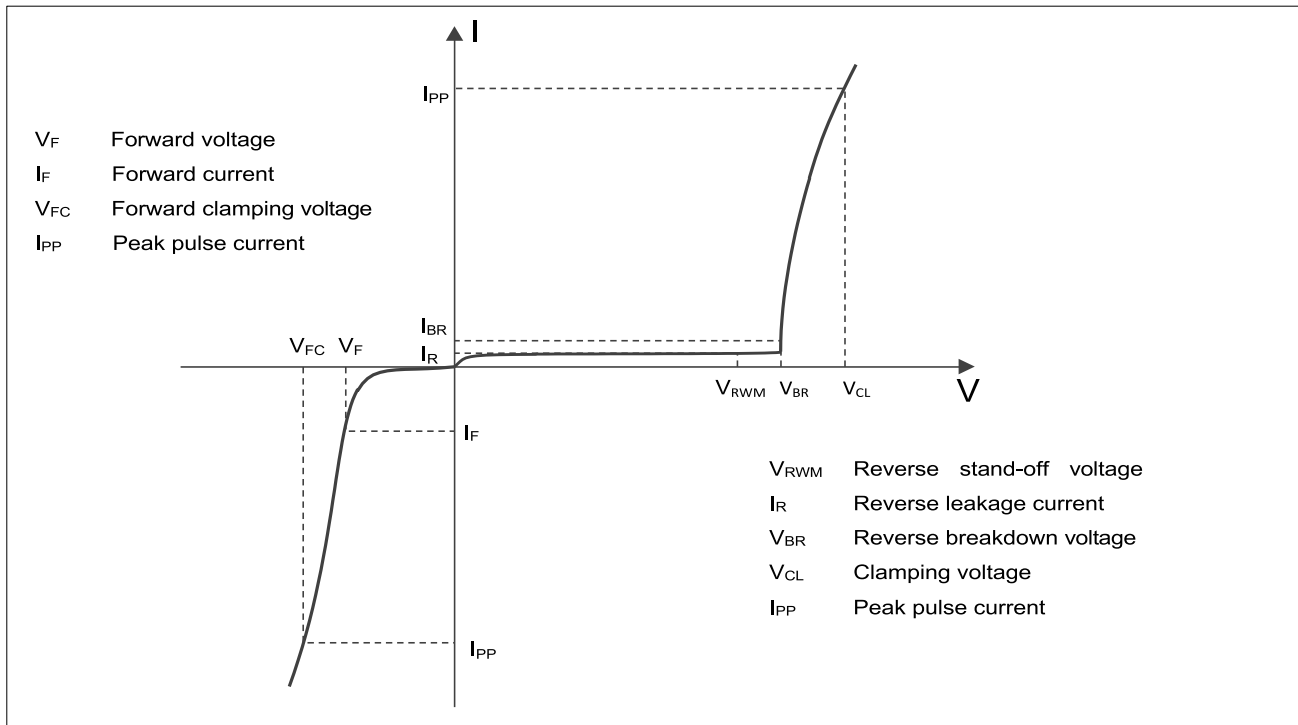
Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	P _{PK}	6000	W
Peak Pulse Current (8/20μs)	I _{PP}	200	A
ESD per IEC 61000-4-2 (Air)	V _{ESD}	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	kV
Lead temperature	T _L	260	°C
Operating Temperature Range	T _{OP}	-40 ~ +85	°C
Storage Temperature Range	T _{STG}	-55 ~ +150	°C

Electrical Characteristics (T_A=25°C unless otherwise specified)

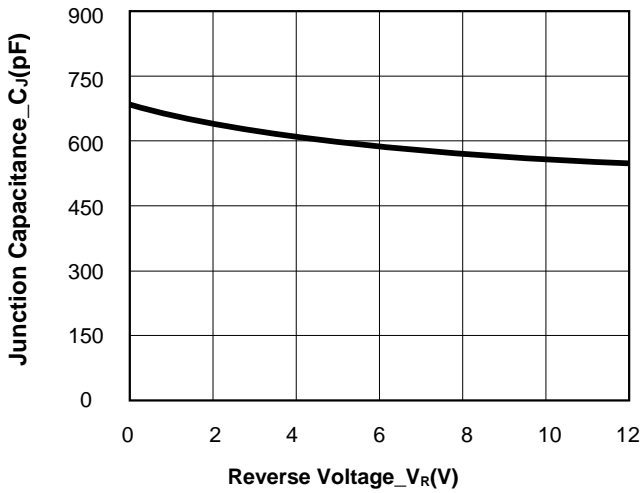
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}			12	V	
Breakdown Voltage	V _{BR}	12.5			V	I _T = 1mA
Reverse Leakage Current	I _R			1	μA	V _{RWM} = 12V
Clamping Voltage	V _C			20	V	I _{PP} = 50A (8/20μs pulse)
Clamping Voltage	V _C			30	V	I _{PP} = 200A (8/0μs pulse)
Junction Capacitance	C _J		670		pF	V _R = 0V, f = 1MHz

Electrical characteristics ($T_A = 25^\circ\text{C}$, unless otherwise noted)

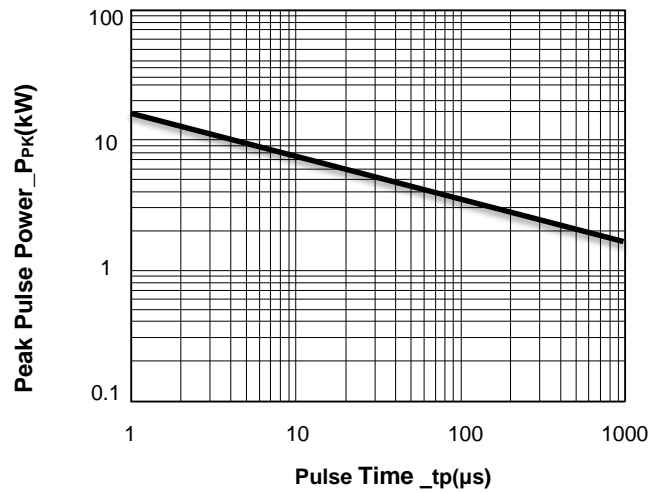


Definitions of electrical characteristics

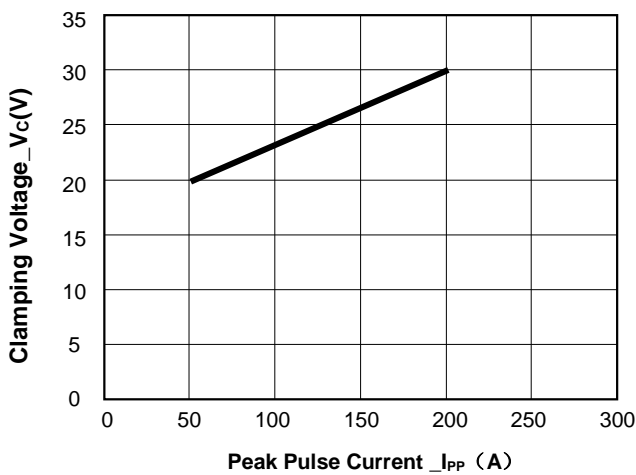
Typical Performance Characteristics (T_A=25°C unless otherwise Specified)



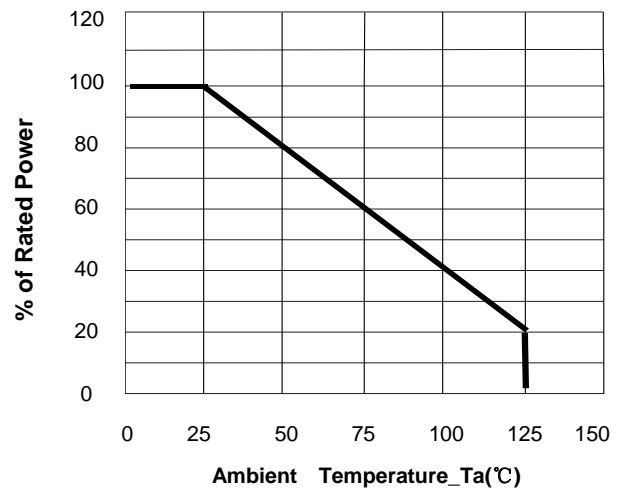
Junction Capacitance vs. Reverse Voltage



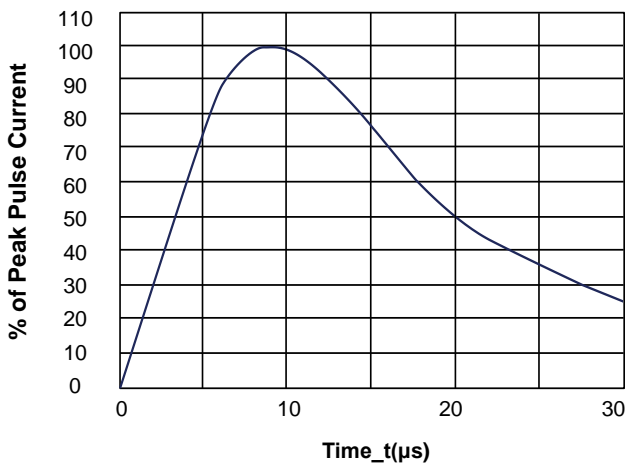
Peak Pulse Power vs. Pulse Time



Clamping Voltage vs. Peak Pulse Current

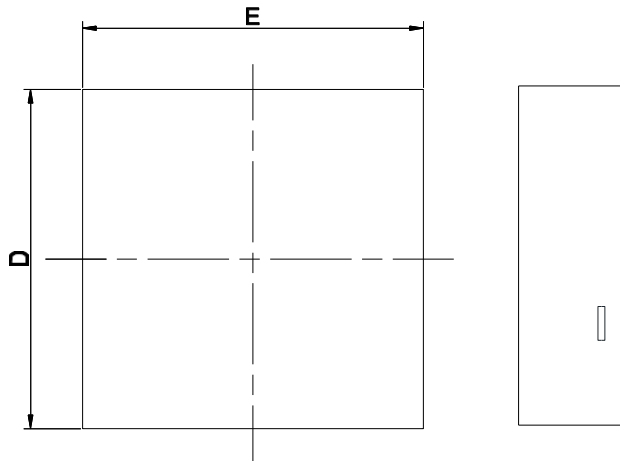


Power Derating Curve

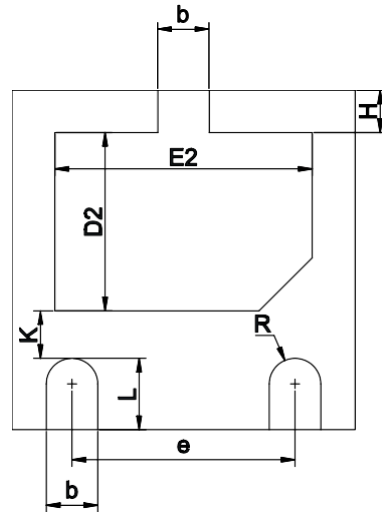


8/20μs Pulse Waveform

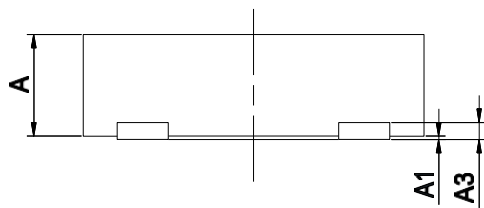
DFN2020-3 Package Outline Drawing



Top View



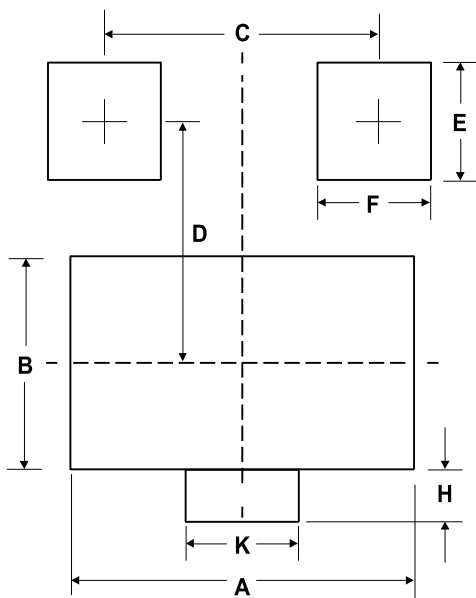
Bottom View



Side View

Symbol	Dimensions In Millimeters		
	Min.	Typ.	Max
A	0.55	0.60	0.65
A1	0.00	0.02	0.05
A3	0.10 REF.		
b	0.25	0.30	0.35
D	1.90	2.00	2.10
E	1.90	2.00	2.10
D2	0.95	1.05	1.15
E2	1.40	1.50	1.60
e	1.20	1.30	1.40
H	0.20	0.25	0.30
K	0.20	0.30	0.40
L	0.35	0.40	0.45
R	0.13	-	-

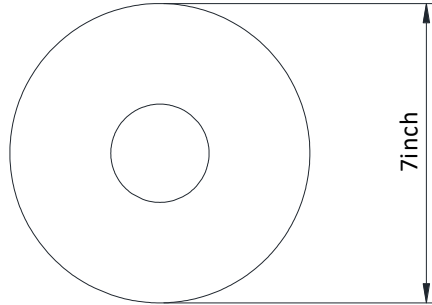
Suggested Land Pattern



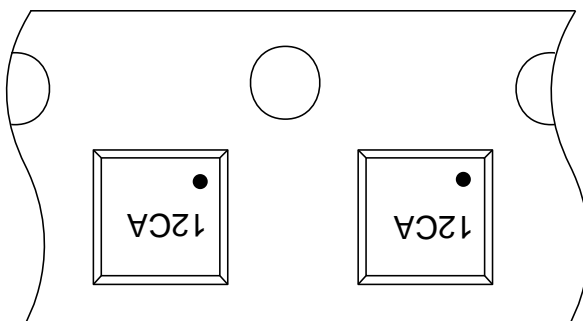
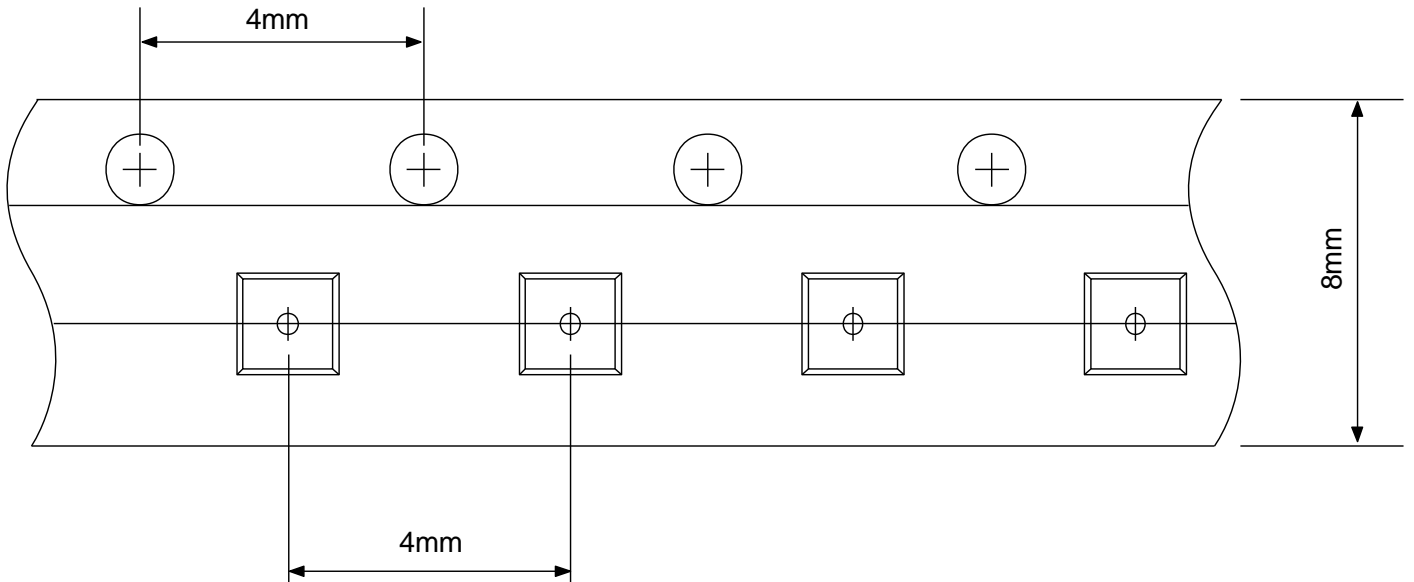
SYM	MILLIMETERS
A	1.60
B	1.10
C	1.30
D	1.05
E	0.50
F	0.40
K	0.40
H	0.25

TAPE AND REEL INFORMATION

Reel Dimensions



Tape Dimensions




User Direction of Feed

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